

UT54ACS109E

Radiation-Hardened

Dual J-K Flip-Flops

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FEATURES

- 0.6µm CRH CMOS Process
 - Latchup immune
- High speed
- Low power consumption
- Wide operating power supply of 3.0V to 5.5V
- Available QML Q or V processes
- 16-lead flatpack

DESCRIPTION

The UT54ACS109E is a dual J- \bar{K} positive triggered flip-flop. A low level at the preset or clear inputs sets or resets the outputs regardless of the other input levels. When preset and clear are inactive (high), data at the J and \bar{K} input meeting the setup time requirements are transferred to the outputs on the positive-going edge of the clock pulse. Following the hold time interval, data at the J and \bar{K} input can be changed without affecting the levels at the outputs. The flip-flops can perform as toggle flip-flops by grounding \bar{K} and tying J high. They also can perform as D flip-flops if J and \bar{K} are tied together.

The devices are characterized over full military temperature range of -55°C to +125°C.

FUNCTION TABLE

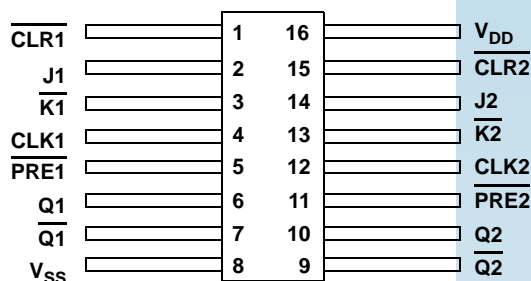
INPUTS					OUTPUT	
$\overline{\text{PRE}}$	$\overline{\text{CLR}}$	CLK	J	\bar{K}	Q	\bar{Q}
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H ¹	H ¹
H	H	↑	L	L	L	H
H	H	↑	H	L	Toggle	
H	H	↑	L	H	No Change	
H	H	↑	H	H	H	L
H	H	L	X	X	No Change	

Note:

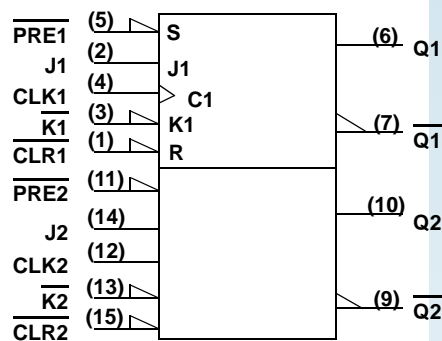
1. The output levels in this configuration are not guaranteed to meet the minimum levels for V_{OH} if the lows at preset and clear are near V_{IL} maximum. In addition, this configuration is nonstable; that is, it will not persist when either preset or clear returns to its inactive (high) level.

PINOUTS

16-Lead Flatpack Top View



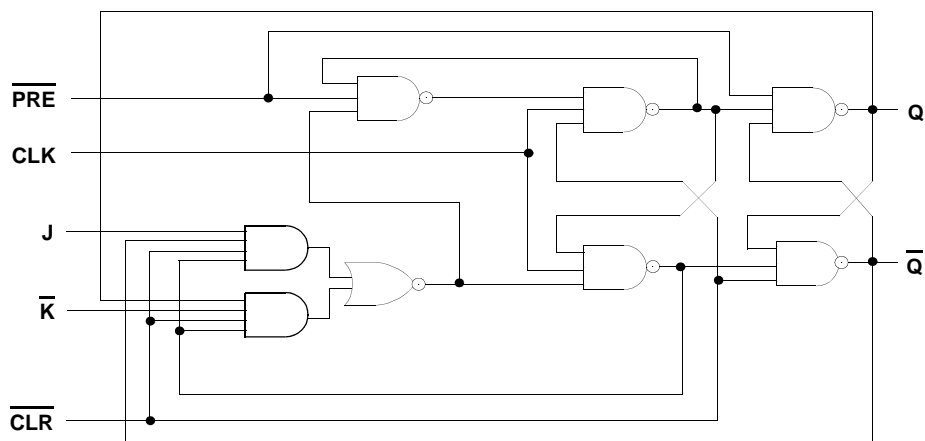
LOGIC SYMBOL



Note:

1. Logic symbol in accordance with ANSI/IEEE standard 91-1984 and IEC Publication 617-12.

LOGIC DIAGRAM



RADIATION HARDNESS SPECIFICATIONS ¹

PARAMETER	LIMIT	UNITS
Total Dose	1.0E6	rads(Si)
SEU Threshold ²	80	MeV-cm ² /mg
SEL Threshold	120	MeV-cm ² /mg
Neutron Fluence	1.0E14	n/cm ²

Notes:

1. Logic will not latchup during radiation exposure within the limits defined in the table.
2. Device storage elements are immune to SEU affects.

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	LIMIT	UNITS
V_{DD}	Supply voltage	-0.3 to 7.0	V
$V_{I/O}$	Voltage any pin	-.3 to $V_{DD} + .3$	V
T_{STG}	Storage Temperature range	-65 to +150	°C
T_J	Maximum junction temperature	+175	°C
T_{LS}	Lead temperature (soldering 5 seconds)	+300	°C
Θ_{JC}	Thermal resistance junction to case	20	°C/W
I_I	DC input current	± 10	mA
P_D	Maximum power dissipation	1	W

Note:

1. Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, functional operation of the device at these or any other conditions beyond limits indicated in the operational sections is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMIT	UNITS
V_{DD}	Supply voltage	3.0 to 5.5	V
V_{IN}	Input voltage any pin	0 to V_{DD}	V
T_C	Temperature range	-55 to + 125	°C

DC ELECTRICAL CHARACTERISTICS FOR THE UT54ACS109E⁷

($V_{DD} = 3.0V$ to $5.5V$; $V_{SS} = 0V$ ⁶; $-55^{\circ}C < T_C < +125^{\circ}C$)

SYMBOL	Description	CONDITION	VDD	MIN	MAX	UNIT
V_{IL}	Low-level input voltage ¹		3.0V		0.9	V
			5.5V		1.65	
V_{IH}	High-level input voltage ¹		3.0V	2.1		V
			5.5V	3.85		
I_{IN}	Input leakage current	$V_{IN} = V_{DD}$ or V_{SS}	5.5V	-1	1	μA
V_{OL}	Low-level output voltage ³	$I_{OL} = 100\mu A$	3.0V		0.25	V
			4.5V		0.25	
V_{OH}	High-level output voltage ³	$I_{OH} = -100\mu A$	3.0V	2.75		V
			4.5V	4.25		
I_{OS}	Short-circuit output current ^{2,4}	$V_O = V_{DD}$ and V_{SS}	3.0V	-100	100	mA
			5.5V	-200	200	
I_{OL}	Low level output current ⁹	$V_{IN} = V_{DD}$ or V_{SS} $V_{OL} = 0.4V$	3.0V	6		mA
			5.5V	8		
I_{OH}	High level output current ⁹	$V_{IN} = V_{DD}$ or V_{SS} $V_{OH} = V_{DD}-0.4V$	3.0V		-6	mA
			5.5V		-8	
P_{total}	Power dissipation ^{2, 8}	$C_L = 50pF$	5.5V		2.9	mW/ MHz
			3.0V		0.8	
I_{DDQ}	Quiescent Supply Current	$V_{IN} = V_{DD}$ or V_{SS}	5.5V		10	μA
C_{IN}	Input capacitance ⁵	$f = 1MHz$	0V		15	pF
C_{OUT}	Output capacitance ⁵	$f = 1MHz$	0V		15	pF

Notes:

- Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions: $V_{IH} = V_{IH(min)} + 20\%$, -0% ; $V_{IL} = V_{IL(max)} + 0\%$, -50% , as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to $V_{IH(min)}$ and $V_{IL(max)}$.
- Supplied as a design limit but not guaranteed or tested.
- Per MIL-PRF-38535, for current density $\leq 5.0E5$ amps/cm², the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765pF/MHz.
- Not more than one output may be shorted at a time for maximum duration of one second.
- Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and V_{SS} at frequency of 1MHz and a signal amplitude of 50mV rms maximum.
- Maximum allowable relative shift equals 50mV.
- All specifications valid for radiation dose $\leq 1E6$ rads(Si) per MIL-STD-883 Method 1019 Condition B.
- Power dissipation specified per switching output.
- This value is guaranteed based on characterization data, but not tested.

AC ELECTRICAL CHARACTERISTICS FOR THE UT54ACS109E²

($V_{DD} = 3.0V$ to $5.5V$; $V_{SS} = 0V$ ¹, $-55^{\circ}C < T_C < +125^{\circ}C$)

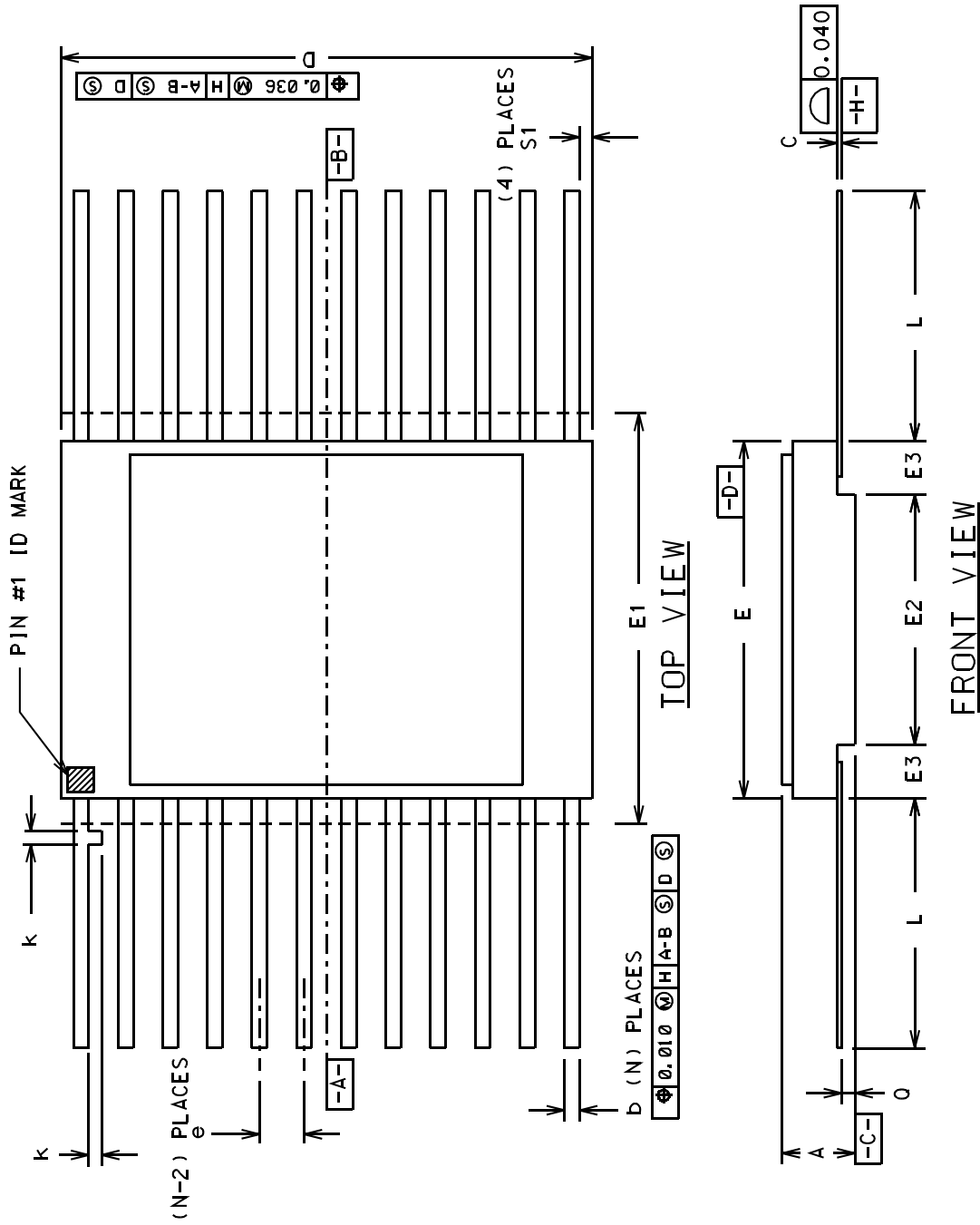
SYMBOL	PARAMETER		V_{DD}	MINIMUM	MAXIMUM	UNIT
t_{PLH1}	CLK to Q, \overline{Q}	$C_L = 30pF$	3.0V & 3.6V	4	23	ns
			4.5V & 5.5V	4	19	
		$C_L = 50pF$	3.0V & 3.6V	4	27	ns
			4.5V & 5.5V	4	23	
t_{PHL1}	CLK to Q, \overline{Q}	$C_L = 30pF$	3.0V & 3.6V	5	27	ns
			4.5V & 5.5V	5	23	
		$C_L = 50pF$	3.0V & 3.6V	5	31	ns
			4.5V & 5.5V	5	27	
t_{PLH2}	\overline{PRE} to Q	$C_L = 30pF$	3.0V & 3.6V	1	16	ns
			4.5V & 5.5V	1	12	
		$C_L = 50pF$	3.0V & 3.6V	1	20	ns
			4.5V & 5.5V	1	16	
t_{PHL2}	\overline{PRE} to \overline{Q}	$C_L = 30pF$	3.0V & 3.6V	1	19	ns
			4.5V & 5.5V	1	15	
		$C_L = 50pF$	3.0V & 3.6V	1	23	ns
			4.5V & 5.5V	1	19	
t_{PLH3}	\overline{CLR} to \overline{Q}	$C_L = 30pF$	3.0V & 3.6V	2	16	ns
			4.5V & 5.5V	2	12	
		$C_L = 50pF$	3.0V & 3.6V	2	20	ns
			4.5V & 5.5V	2	16	
t_{PHL3}	\overline{CLR} to Q	$C_L = 30pF$	3.0V & 3.6V	2	19	ns
			4.5V & 5.5V	2	15	
		$C_L = 50pF$	3.0V & 3.6V	2	23	ns
			4.5V & 5.5V	2	19	
f_{MAX}	Maximum clock frequency	$C_L = 50pF$	3.0V, 4.5V, and 5.5V		62	MHz
t_{SU1}	\overline{PRE} or \overline{CLR} inactive setup time before CLK \uparrow	$C_L = 50pF$	3.0V, 4.5V, and 5.5V	5		ns

t_{SU2}	Data setup time before CLK \uparrow	$C_L = 50\text{pF}$	3.0V, 4.5V, and 5.5V	5		ns
t_H^3	Data hold time after CLK \uparrow	$C_L = 50\text{pF}$	3.0V, 4.5V, and 5.5V	3		ns
t_W	Minimum pulse width $\overline{\text{PRE}}$ or $\overline{\text{CLR}}$ low CLK high CLK low	$C_L = 50\text{pF}$	3.0V, 4.5V, and 5.5V	8		ns

Notes:

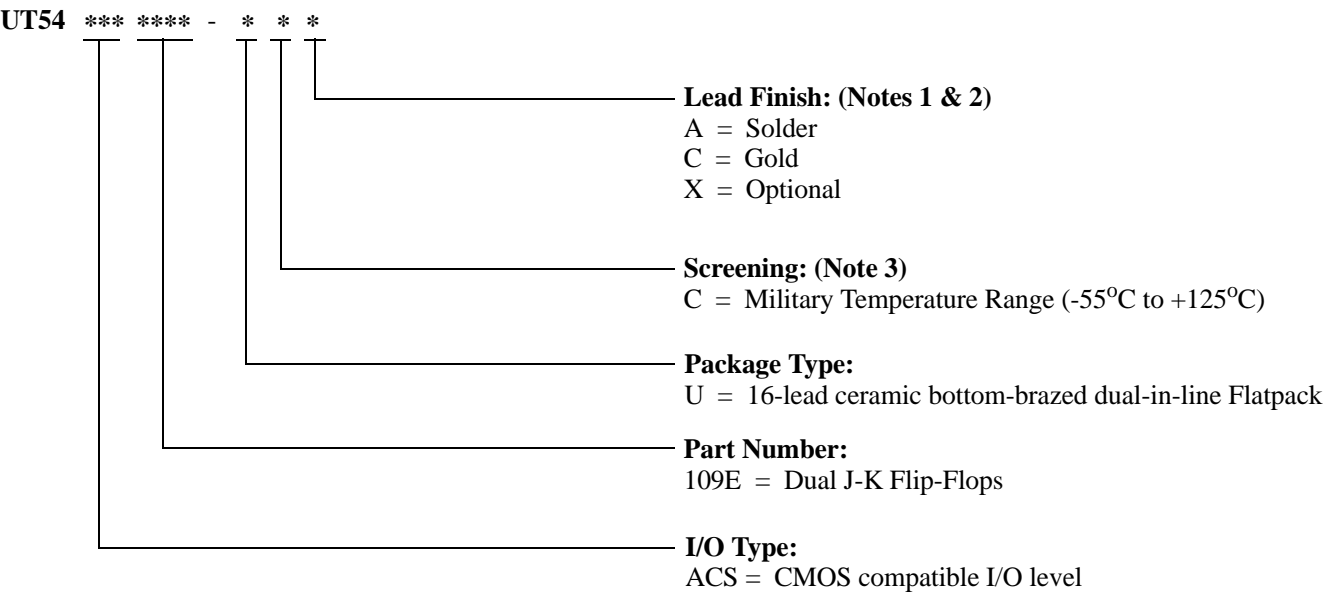
1. Maximum allowable relative shift equals 50mV.
2. All specifications valid for radiation dose $\leq 1\text{E}6$ rads(Si) per MIL-STD-883 Method 1019 Condition B.
3. Based on characterization, hold time (t_H) of 0ns can be assumed if data setup time (t_{SU2}) is $\geq 10\text{ns}$. This is guaranteed, but not tested

Packaging



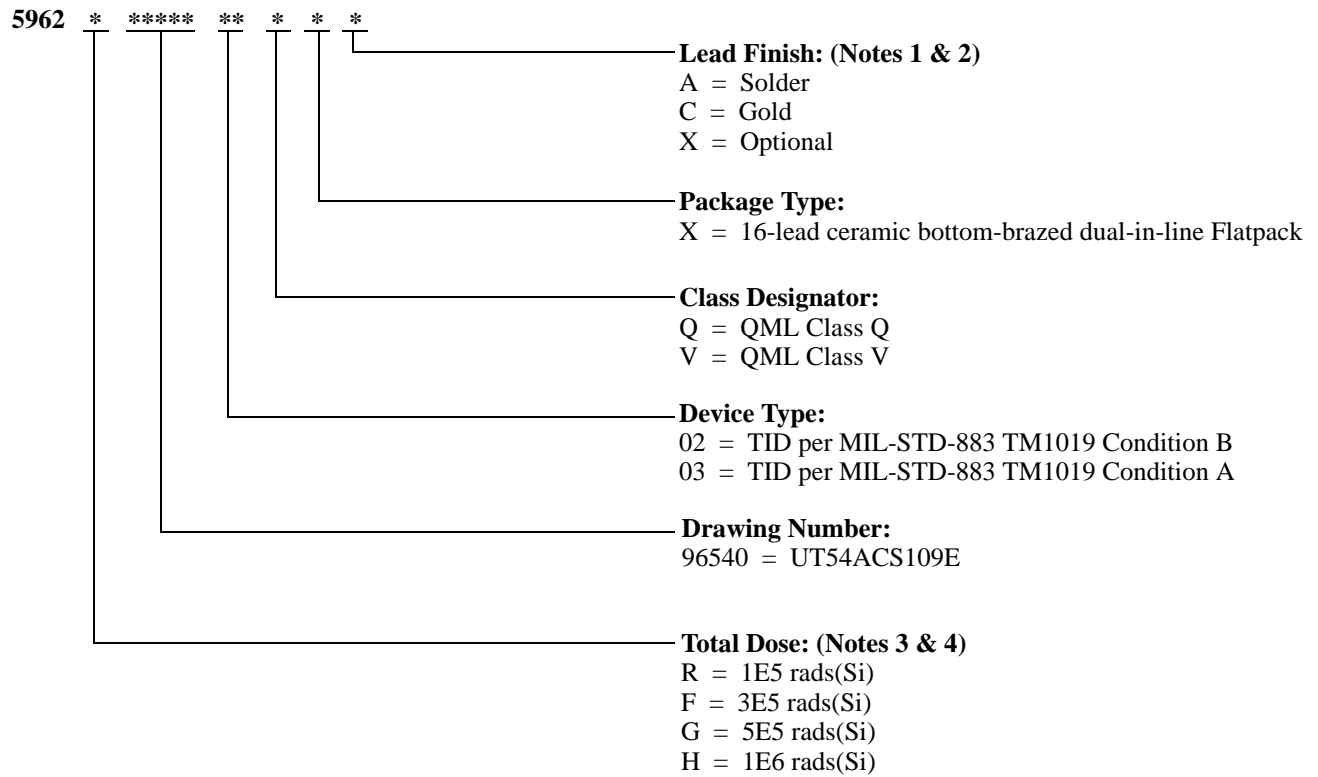
PKG CONFIG	LEAD COUNT	MLL-STD 1835 DWG CONF B	DIMENSION SYMBOLS												
			A	b	c	D	E	E1	E2	E3	e	k	L	Q	S1
-03	14	F-2A	0.115 0.045	0.022 0.015	0.009 0.004	0.390 -----	0.260 0.235	0.290 -----	----- 0.130	----- 0.030	0.050 BSC	0.015 0.008	0.370 0.270	0.045 0.026	----- 0.005
-04	16	F-5A	0.115 0.045	0.022 0.015	0.009 0.004	0.440 -----	0.285 0.245	0.315 -----	----- 0.130	----- 0.030	0.050 BSC	0.015 0.008	0.370 0.250	0.045 0.026	----- 0.005
-05	20	F-9A	0.115 0.045	0.022 0.015	0.009 0.004	0.540 -----	0.300 0.245	0.330 -----	----- 0.130	----- 0.030	0.050 BSC	0.015 0.008	0.370 0.250	0.045 0.026	----- 0.000

Ordering Information UT54ACS109E



- Notes:
- 1. Lead finish (A, C, or X) must be specified.
 - 2. If an "X" is specified when ordering, then the part marking will match the lead finish and will be either "A" (solder) or "C" (gold).
 - 3. Military Temperature Range flow per Aeroflex Manufacturing Flows Document. Devices have 48 hours of burn-in and are test at -55°C, room temperature, and 125°C. Radiation characteristics are neither tested nor guaranteed and may not be specified.

UT54ACS109E: SMD



Notes:

1. Lead finish (A, C, or X) must be specified.
2. If an "X" is specified when ordering, then the part marking will match the lead finish and will be either "A" (solder) or "C" (gold).
3. Total dose radiation must be specified when ordering. QML V is not available without radiation testing.
4. Device type 02 is only offered with a TID tolerance guarantee of 3E5 rads(Si) or 1E6 rads(Si) and is tested in accordance with MIL-STD-883 Test Method 1019 Condition B. Device type 03 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.

COLORADO

Toll Free: 800-645-8862
Fax: 719-594-8468

INTERNATIONAL

Tel: 805-778-9229
Fax: 805-778-1980

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Tel: 719-594-8017
Fax: 719-594-8468

www.aeroflex.com info-ams@aeroflex.com

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